Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	511570	(electrically adj3 memory) or (erasable adj3 memory) or (\$1eprom) or (flash or non-volatile or (non adj volatile) adj3 (memory or cell)) or ((non adj volatile) or nonvolatile or non-volatile) adj3 (memory or cell) or nvm	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/19 17:38
L2	11019	voltage adj regulation	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/19 17:38
L3	1349	L1 and L2	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/19 17:39
L4	57	3 and (current adj sink\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/19 17:40
L5	45	4 and @ad<="20030228"	US-PGPUB; USPAT; EPO; JPO;	OR	ON	2006/04/19 17:40
			DERWENT; IBM_TDB			
L6	0	5 and (program\$3 adj load adj circuit) and memory	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/19 17:41
L7	0	((non adj volatile adj memory) and (voltage adj regulation adj system) and (multiword adj programming) and (corresponding adj circuits) and (memory adj cell adj content)and (current adj sinking)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/19 17:44
L8	21	martines-ignazio.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/19 17:44
L9	3	scardaci-massimo.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/19 17:45

S1	480876	(electrically adj3 memory) or (erasable adj3 memory) or (\$1eprom) or (flash or non-volatile or (non adj volatile) adj3 (memory or cell)) or ((non adj volatile) or nonvolatile or non-volatile) adj3 (memory or cell) or nvm	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/18 13:45
S2	10582	voltage adj regulation	US-PGPUB;	OR	ON	2005/12/01 15:06
*			USPAT; EPO; JPO; DERWENT; IBM_TDB	· · · · · · · · · · · · · · · · · · ·		
S3	1243	S1 and S2	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/18 13:44
S4	14	S3 and (memory adj cell adj matrix)	US-PGPUB; USPAT; EPO; JPO; DERWENT;	OR	ON	2005/11/18 13:57
			IBM_TDB			
S5	69	S3 and (column adj decoder)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/18 13:56
S6	78.	S3 and ((memory adj cell adj matrix) or (column adj decoder))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	+OR	ON	2005/12/01 15:06
S7 .	36	(program\$3 adj load adj circuit) and memory	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/19 17:40
S8	3	(non adj.volatile) and falsh	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/30 16:30
S9	46361	(non adj volatile) and flash	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/01 15:05

S10	12273	S9 and eras\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/18 16:24
S11	11157	S10 and read\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/18 16:25
S12	8649	S11 and writ\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2005/11/18 16:25
S13	178	S12 and (program\$3 adj load)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/18 16:25
S14	110	S13 and ground	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/18 16:31
S15	69	S14 and active	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/18 16:27
S16	3	"6603681"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/30 16:30
S17	3	(non adj volatile) and falsh	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/01 14:30
S18	483783	(electrically adj3 memory) or (erasable adj3 memory) or (\$1eprom) or (flash or non-volatile or (non adj volatile) adj3 (memory or cell)) or ((non adj volatile) or nonvolatile or non-volatile) adj3 (memory or cell) or nvm	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR ·	ON	2005/12/01 15:04

S19						
319	1206	365/185.21	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/01 15:06
S20	24	S19 and (voltage adj regulation)	US-PGPUB;	OR	ON	2005/12/01 15:06
			USPAT; EPO; JPO; DERWENT; IBM_TDB			
S21	467	S19 and ((non adj volatile) and flash)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/01 15:07
S22	158	S21 and ((memory adj cell adj	US-PGPUB;	OR	ON	2005/12/01 15:06
		matrix) or (column adj decoder))	USPAT; EPO; JPO;			
			DERWENT;			
Ē	•		IBM_TDB			
S23	7	S22 and (voltage adj regulation)	US-PGPUB; USPAT; EPO; JPO; DERWENT;	OR	ON	2005/12/01 15:06
			IBM_TDB			
S24	2314	365/185.18	US-PGPUB;	OR	ON	2005/12/01 15:07
			USPAT;			
			EPO; JPO; DERWENT;			
			IBM_TDB			
S25	57	S24 and (voltage adj regulation)	US-PGPUB;	OR	ON .	2005/12/01 15:07
			USPAT; EPO; JPO;			
			DERWENT;			
			IBM_TDB			
S26	26	S25 and ((non adj volatile) and	US-PGPUB;	OR.	ON	2005/12/01 15:07
	*	flash)	USPAT; EPO; JPO;			
	·		DERWENT;	-		
		* * *	IBM_TDB			
S27	777	365/185.19	US-PGPUB; USPAT;	OR	ON	2005/12/01 15:07
			EPO; JPO;			
			DERWENT; IBM_TDB			
S28	11	S27 and (voltage adj regulation)	US-PGPUB;	OR	ON	2005/12/01 15:07
		(USPAT;	J.,	J.,	2555, 12, 51 15.57
			EPO; JPO; DERWENT;			·
	·		IBM_TDB			* . * .

S29	1156	365/185.09	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/01 15:07
S30	455	S29 and ((non adj volatile) and flash)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/01 15:07
S31	4	S30 and (voltage adj regulation)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/01 15:07